

RW1C015UNT2R

RW1C015UNT2R Information

For Reference Only	Part Number	RW1C015UNT2R
	Manufacturer	Rohm Semiconductor
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH 20V 1.5A WEMT6
	Package	SOT-563, SOT-666
		For the pricing/inventory/lead time, please contact
		us
		Website: https://www.heisener.com
		E-mail: salesdept@heisener.com



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RW1C015UNT2R Specifications

Manufacturer Part Number	RW1C015UNT2R
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SOT-563, SOT-666
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	1.5A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs(th) (Max) @ Id	1V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	1.8nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	110pF @ 10V
Vgs (Max)	±10V
FET Feature	-
Power Dissipation (Max)	400mW (Ta)
Rds On (Max) @ Id, Vgs	180 mOhm @ 1.5A, 4.5V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	6-WEMT
Package / Case	SOT-563, SOT-666
	Report errors?

RW1C015UNT2R Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RW1C015UNT2R Payment Methods





If you have any question about RW1C015UNT2R, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com